NSN 5961-01-367-1963

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-367-1963 **Inclosure Material:** Plastic **Overall Length:** 0.594 inches **Terminal Length:** 0.550 inches **Overall Height:** 0.190 inches **Overall Width:** 0.415 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Mounting Method:** Terminal and unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 drain to source voltage **Current Rating Per Characteristic:** 145.00 amperes off-state current, peak **Power Rating Per Characteristic:** 125.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 90.0 degrees celsius junction **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli